

<IGBT Modules>

CM600DY-24T

HIGH POWER SWITCHING USE INSULATED TYPE



Dimension in mm

RoHS Directive compliantUL Recognized under UL1557, File No.E323585

dual switch (half-bridge)

APPLICATION

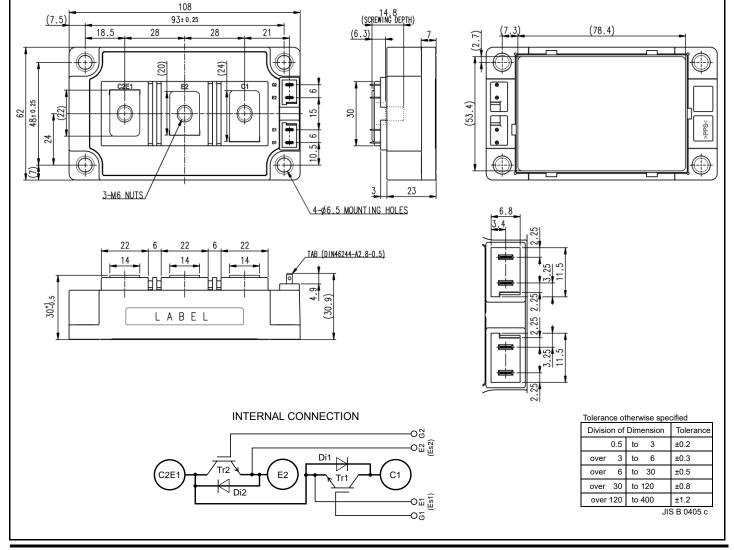
AC Motor Control, Motion/Servo Control, Power supply, etc.

OPTION (Below options are available.)

•PC-TIM (Phase Change Thermal Interface Material) pre-apply (Note8)

•VcEsat selection for parallel connection

OUTLINE DRAWING & INTERNAL CONNECTION



MAXIMUM RATINGS (Tvj=25 °C, unless otherwise specified)

Symbol	Item	Conditions	Rating	Unit	
V _{CES}	Collector-emitter voltage	G-E short-circuited	1200	V	
V_{GES}	Gate-emitter voltage	C-E short-circuited	± 20	V	
lc		DC, T _C =144 °C* (Note2, 4)	600	•	
I _{CRM}	Collector current	Pulse, Repetitive (Note3)	1200	A	
P _{tot}	Total power dissipation	T _c =25 °C (Note2, 4)	6250	W	
IE (Note1)		DC (Note2)	600	•	
IERM (Note1)	Emitter current	Pulse, Repetitive (Note3)	1200	A	
Visol	Isolation voltage	Terminals to base plate, RMS, f=60 Hz, AC 1 min	4000	V	
T _{jmax}	Maximum junction temperature	Instantaneous event (overload) (Note8)	175	°C	
T _{Cmax}	Maximum case temperature	(Note4,8)	150*	C	
Tjop	Operating junction temperature	Continuous operation (under switching) (Note8)	-40 ~ +150	°C	
T _{stg}	Storage temperature	-	-40 ~ +150*	1	

ELECTRICAL CHARACTERISTICS (Tvj=25 °C, unless otherwise specified)

Symbol	Itom	Conditions		Limits			Linit
Symbol	Item	Conditions		Min.	Тур.	Max.	Unit
I _{CES}	Collector-emitter cut-off current	V _{CE} =V _{CES} , G-E short-circuited		-	-	1.0	mA
I _{GES}	Gate-emitter leakage current	V _{GE} =V _{GES} , C-E short-circuited		-	-	0.5	μA
$V_{\text{GE(th)}}$	Gate-emitter threshold voltage	I _C =60 mA, V _{CE} =10 V		5.4	6.0	6.6	V
		I _C =600 A, V _{GE} =15 V,	T _{vj} =25 °C	-	1.75	2.05	V
V _{CEsat}		Refer to the figure of test circuit	T _{vj} =125 °C	-	2.00	-	
(Terminal)		(Note5)	T _{vj} =150 °C	-	2.10	-	
	Collector-emitter saturation voltage	I _C =600 A,	T _{vj} =25 °C	-	1.55	1.80	V
V _{CEsat}		V _{GE} =15 V,	T _{vj} =125 °C	-	1.75	-	
(Chip)		(Note5)	T _{vj} =150 °C	-	1.80	-	
Cies	Input capacitance	V _{CE} =10 V, G-E short-circuited		-	-	123	nF
C _{oes}	Output capacitance			-	-	3.6	
Cres	Reverse transfer capacitance			-	-	1.5	
Q _G	Gate charge	V _{CC} =600 V, I _C =600 A, V _{GE} =15 V		-	3.7	-	μC
t _{d(on)}	Turn-on delay time	V _{cc} =600 V, I _c =600 A, V _{GE} =±15 V, R _G =1.0 Ω, Inductive load		-	-	500	ns
t _r	Rise time			-	-	200	
$t_{d(off)}$	Turn-off delay time			-	-	600	
t _f	Fall time			-	-	300	
(Nists 4)		I _E =600 A, G-E short-circuited,	T _{vj} =25 °C	-	1.85	2.25	
V _{EC} (Note.1)	Terminal) Emitter-collector voltage (Note.1) Chip)	Refer to the figure of test circuit	T _{vj} =125 °C	-	2.00	-	V
(Terminal)		(Note5)	T _{vj} =150 °C	-	2.00	-	
		I _E =600 A,	T _{vj} =25 °C	-	1.65	2.00	
		G-E short-circuited, (Note5)	T _{vj} =125 °C	-	1.65	-	V
(Cnip)			T _{vj} =150 °C	-	1.65	-	
t _{rr} ^(Note1)	Reverse recovery time	V _{CC} =600 V, I _E =600 A, V _{GE} =±15 V,		-	-	400	ns
Q _{rr} (Note1)	Reverse recovery charge	R_{G} =1.0 Ω , Inductive load		-	60	-	μC
Eon	Turn-on switching energy per pulse	V _{CC} =600 V, I _C =I _E =600 A,		-	56.6	-	
E _{off}	Turn-off switching energy per pulse	V _{GE} =±15 V, R _G =1.0 Ω, T _{vj} =150 °C,		-	64.3	-	mJ
Err (Note1)	Reverse recovery energy per pulse	Inductive load		-	38.2	-	mJ
R _{CC'+EE'}	Internal lead resistance	Main terminals-chip, per switch, Tc=25	°C (Note4)	-	0.3	-	mΩ
r _q	Internal gate resistance	Per switch		-	0.67	-	Ω

*: The value of PC-TIM applied module is limited by the heat resistant temperature of PC-TIM.

THERMAL RESISTANCE CHARACTERISTICS

Symbol	Item	Conditions	Limits			Unit
		Conditions	Min.	Тур.	Max.	Unit
$R_{th(j-c)Q}$	Thermal resistance	Junction to case, per Inverter IGBT (Note4)	-	-	24	K/kW
$R_{th(j-c)D}$		Junction to case, per Inverter FWD (Note4)	-	-	42	r\/KVV
$R_{th(c-s)}$	Contact thermal resistance	Case to heat sink, per 1 module Thermal grease applied (Note4,6,8)	-	13.3	-	K/kW

MECHANICAL CHARACTERISTICS

Symbol	ltom	Conditions		Limits			Linit
	Item			Min.	Тур.	Max.	Unit
Mt	Mounting torque	Main terminals	M 6 screw	3.5	4.0	4.5	N∙m
Ms	Mounting torque	Mounting to heat sink	M 6 screw	3.5	4.0	4.5	N∙m
ds	Creepage distance	Terminal to terminal		17.3	-	-	mm
		Terminal to base plate		25.3	-	-	
d _a (Clearance	Terminal to terminal		12.6	-	-	
	Clearance	Terminal to base plate		21.8	-	-	mm
ec	Flatness of base plate	On the centerline X, Y (Note7)		±0	-	+200	μm
m	mass	-		-	260	-	g

*. This product is compliant with the Restriction of the Use of Certain Hazardous Substances in Electrical and Electronic Equipment (RoHS) directive 2011/65/EU and (EU) 2015/863.EU.

Note1. Represent ratings and characteristics of the anti-parallel, emitter-collector free-wheeling diode (FWD).

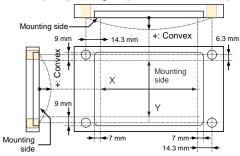
2. Junction temperature (T $_{\nu j}$) should not increase beyond T $_{\nu j\,m\,a\,x}$ rating.

3. Pulse width and repetition rate should be such that the device junction temperature (T_{vj}) dose not exceed T_{vjmax} rating.

4. Case temperature (T_c) and heat sink temperature (T_s) are defined on the each surface (mounting side) of base plate and heat sink just under the chips. Refer to the figure of chip location.

5. Pulse width and repetition rate should be such as to cause negligible temperature rise. Refer to the figure of test circuit.

- 6. Typical value is measured by using thermally conductive grease of λ =3.0 W/(m·K)/D_(C-S)=50 µm.
- 7. The base plate (mounting side) flatness measurement points (X, Y) are shown in the following figure.



8. Long term performance related to thermal conductive grease and PC-TIM (including but not limited to aspects such as the increase of thermal resistance due to pumping out, etc.) should be verified under your specific application conditions. Each temperature condition (T_{vj max}, T_{vj op}, T_{C max}) must be maintained below the maximum rated temperature throughout consideration of the temperature rise even for long term usage.

<IGBT Modules> CM600DY-24T HIGH POWER SWITCHING USE INSULATED TYPE

RECMENDED OPERATING CONDITIONS

Symbol	Itom	Conditions	Limits			Unit
	Item		Min.	Тур.	Max.	Unit
V _{cc}	(DC) Supply voltage	Applied across C1-E2 terminals	-	600	850	V
V_{GEon}	Gate (-emitter drive) voltage	Applied across G1-Es1/G2-Es2 terminals	13.5	15.0	16.5	V
R _G	External gate resistance	Per switch	1.0	-	10	Ω

CHIP LOCATION (Top view)

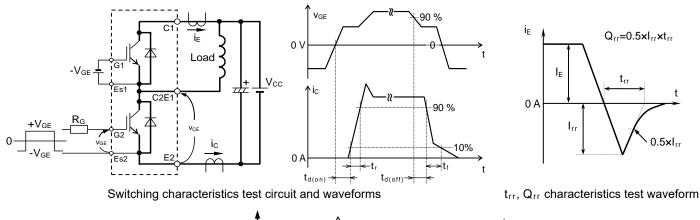
(108)(93) 50.4 72.4 δ ∞ 61.4 0 32. 21 Œ ÷ 44.8 44.8 DiazenTr2 Tr22 Di2 Tr2 C1 44.2 (62) (48) E1 T<u>i</u>l1⊢Dii1 Tr1 18.7 17.9-Tr1—D∔1⊣ G + + 0 ф 0 ¢ Œ 66.4 37.9-8 77.4-0 27 48. LABEL SIDE

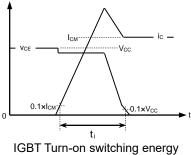
Tr1/Tr2: IGBT, Di1/Di2: FWD

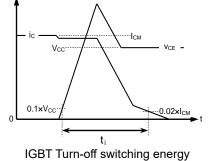
Dimension in mm, tolerance: ±1 mm

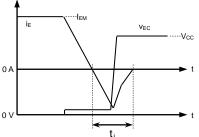
<IGBT Modules> CM600DY-24T HIGH POWER SWITCHING USE INSULATED TYPE

TEST CIRCUIT AND WAVEFORMS







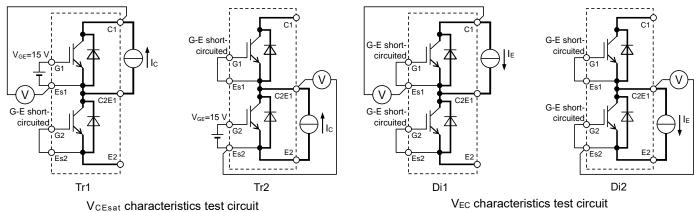


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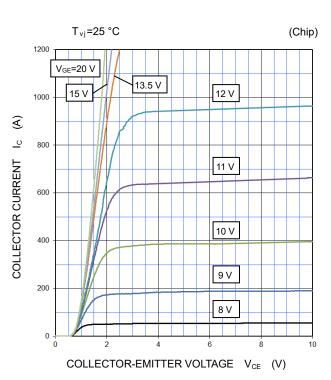
FWD Reverse recovery energy

Turn-on / Turn-off switching energy and Reverse recovery energy test waveforms (Integral time instruction drawing)

TEST CIRCUIT

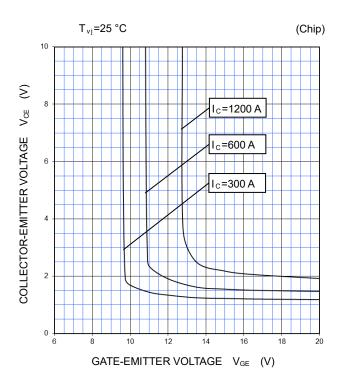


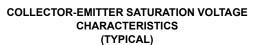
PERFORMANCE CURVES

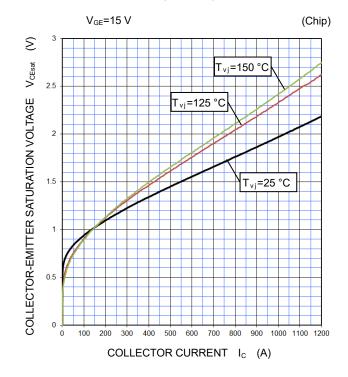


OUTPUT CHARACTERISTICS (TYPICAL)

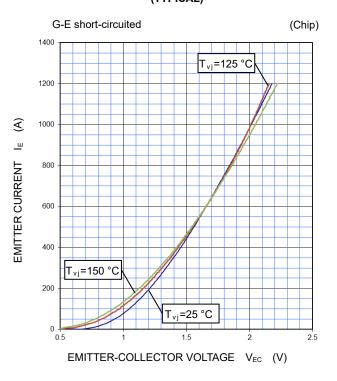
COLLECTOR-EMITTER VOLTAGE CHARACTERISTICS (TYPICAL)



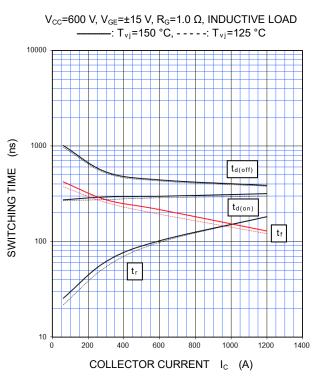




FREE WHEELING DIODE FORWARD CHARACTERISTICS (TYPICAL)

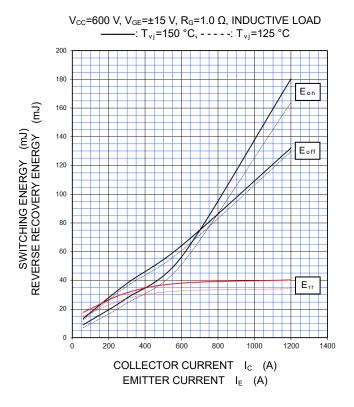


PERFORMANCE CURVES



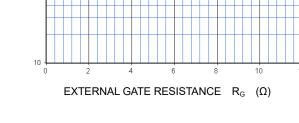
HALF-BRIDGE SWITCHING CHARACTERISTICS (TYPICAL)

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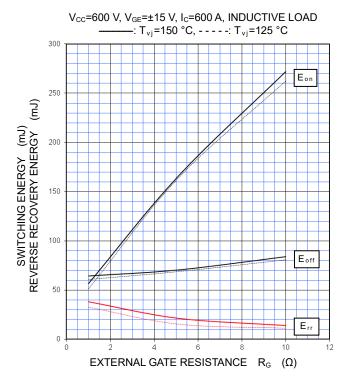


(TYPICAL) $V_{CC}=600 \text{ V}, V_{GE}=\pm 15 \text{ V}, I_C=600 \text{ A}, \text{INDUCTIVE LOAD}$ $\therefore T_{vj}=150 \text{ °C}, ----: T_{vj}=125 \text{ °C}$ 1000 (100)

HALF-BRIDGE SWITCHING CHARACTERISTICS

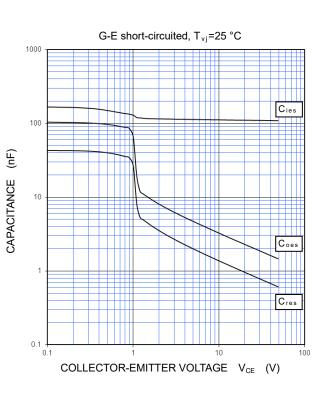


HALF-BRIDGE SWITCHING CHARACTERISTICS (TYPICAL)



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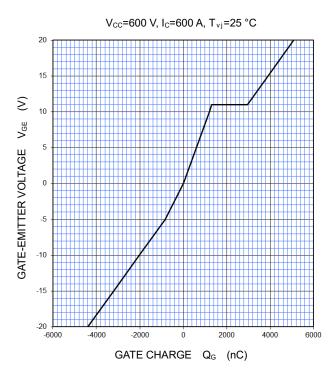
PERFORMANCE CURVES

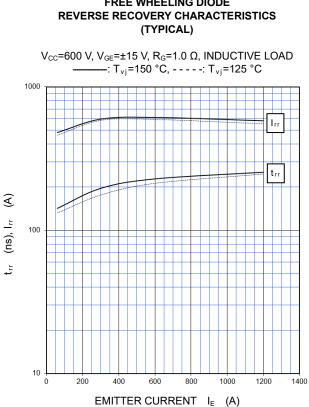


CAPACITANCE CHARACTERISTICS

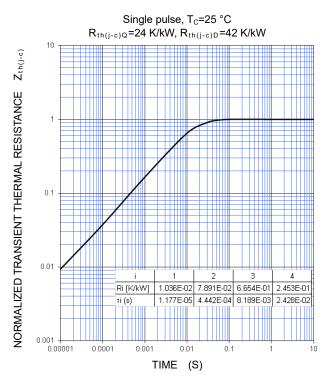
(TYPICAL)

GATE CHARGE CHARACTERISTICS (TYPICAL)





TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (MAXIMUM)

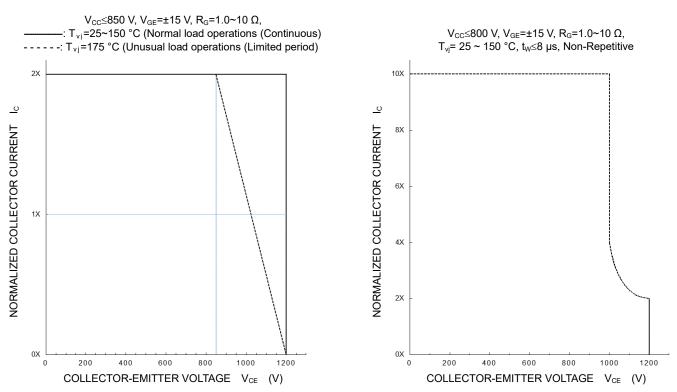


FREE WHEELING DIODE

Publication Date : December 2020

PERFORMANCE CURVES

TURN-OFF SWITCHING SAFE OPERATING AREA (REVERSE BIAS SAFE OPERATING AREA) (MAXIMUM)



Note: The characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

SHORT-CIRCUIT SAFE OPERATING AREA

(MAXIMUM)

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